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#### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

#### Applications of "[Embedded - Microcontrollers](#)"

##### Details

Product Status	Active
Core Processor	RL78
Core Size	16-Bit
Speed	32MHz
Connectivity	CSI, I <sup>2</sup> C, LINbus, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	48
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	8K x 8
RAM Size	48K x 8
Voltage - Supply (Vcc/Vdd)	1.6V ~ 5.5V
Data Converters	A/D 12x8/10b; D/A 2x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-WFLGA
Supplier Device Package	64-FLGA (5x5)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f104llala-w0">https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f104llala-w0</a>

○ ROM, RAM capacities

Flash ROM	Data flash	RAM	RL78/G14			
			30 pins	32 pins	36 pins	40 pins
192 KB	8 KB	20 KB	—	—	—	R5F104EH
128 KB	8 KB	16 KB	R5F104AG	R5F104BG	R5F104CG	R5F104EG
96 KB	8 KB	12 KB	R5F104AF	R5F104BF	R5F104CF	R5F104EF
64 KB	4 KB	5.5 KB Note	R5F104AE	R5F104BE	R5F104CE	R5F104EE
48 KB	4 KB	5.5 KB Note	R5F104AD	R5F104BD	R5F104CD	R5F104ED
32 KB	4 KB	4 KB	R5F104AC	R5F104BC	R5F104CC	R5F104EC
16 KB	4 KB	2.5 KB	R5F104AA	R5F104BA	R5F104CA	R5F104EA

Flash ROM	Data flash	RAM	RL78/G14			
			44 pins	48 pins	52 pins	64 pins
512 KB	8 KB	48 KB Note	—	R5F104GL	—	R5F104LL
384 KB	8 KB	32 KB	—	R5F104GK	—	R5F104LK
256 KB	8 KB	24 KB Note	R5F104FJ	R5F104GJ	R5F104JJ	R5F104LJ
192 KB	8 KB	20 KB	R5F104FH	R5F104GH	R5F104JH	R5F104LH
128 KB	8 KB	16 KB	R5F104FG	R5F104GG	R5F104JG	R5F104LG
96 KB	8 KB	12 KB	R5F104FF	R5F104GF	R5F104JF	R5F104LF
64 KB	4 KB	5.5 KB Note	R5F104FE	R5F104GE	R5F104JE	R5F104LE
48 KB	4 KB	5.5 KB Note	R5F104FD	R5F104GD	R5F104JD	R5F104LD
32 KB	4 KB	4 KB	R5F104FC	R5F104GC	R5F104JC	R5F104LC
16 KB	4 KB	2.5 KB	R5F104FA	R5F104GA	—	—

Flash ROM	Data flash	RAM	RL78/G14	
			80 pins	100 pins
512 KB	8 KB	48 KB Note	R5F104ML	R5F104PL
384 KB	8 KB	32 KB	R5F104MK	R5F104PK
256 KB	8 KB	24 KB Note	R5F104MJ	R5F104PJ
192 KB	8 KB	20 KB	R5F104MH	R5F104PH
128 KB	8 KB	16 KB	R5F104MG	R5F104PG
96 KB	8 KB	12 KB	R5F104MF	R5F104PF

The flash library uses RAM in self-programming and rewriting of the data flash memory.

The target products and start address of the RAM areas used by the flash library are shown below.

R5F104xD (x = A to C, E to G, J, L): Start address FE900H

R5F104xE (x = A to C, E to G, J, L): Start address FE900H

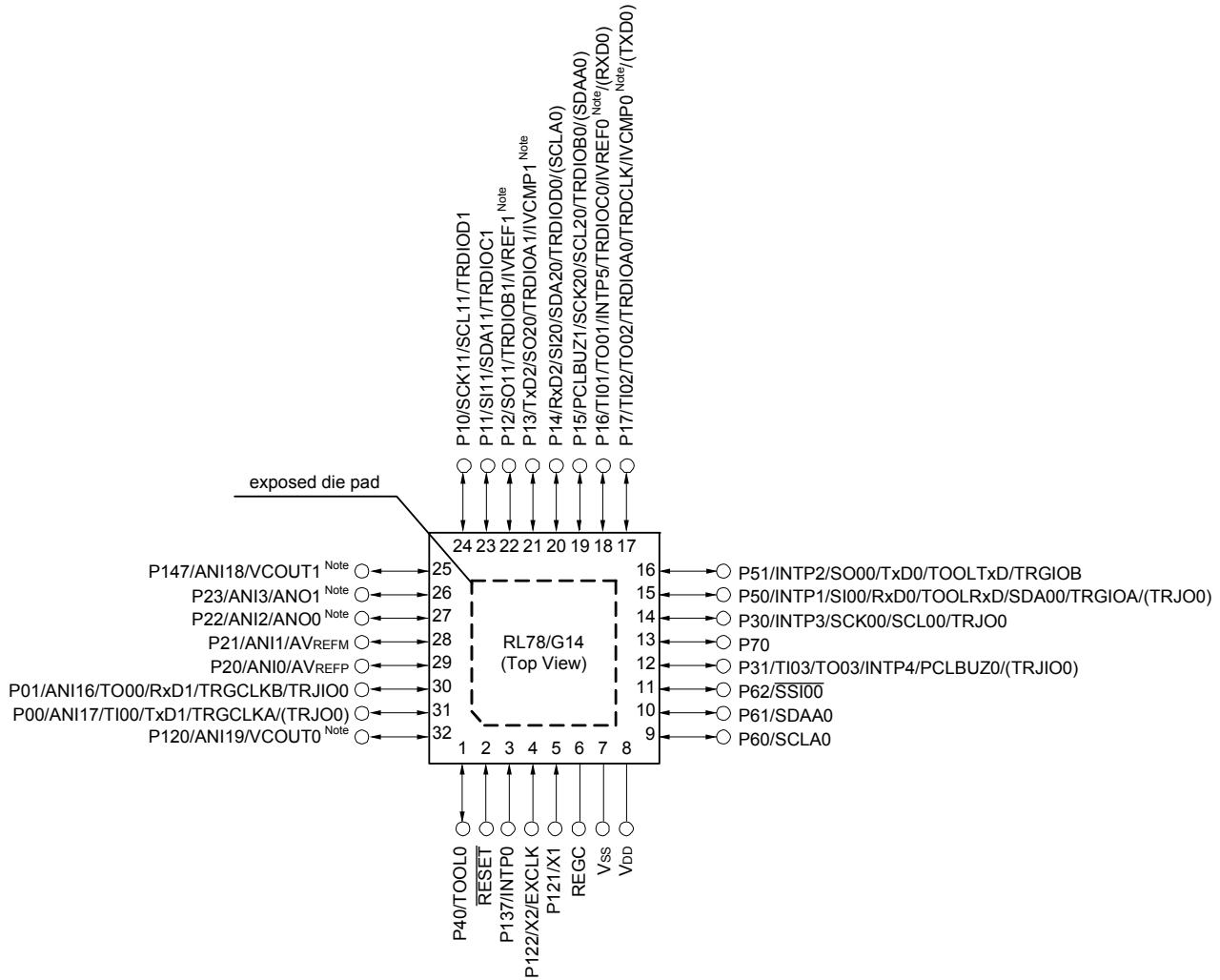
R5F104xJ (x = F, G, J, L, M, P): Start address F9F00H

R5F104xL (x = G, L, M, P): Start address F3F00H

For the RAM areas used by the flash library, see **Self RAM list of Flash Self-Programming Library for RL78 Family (R20UT2944)**.

### 1.3.2 32-pin products

- 32-pin plastic HWQFN (5 × 5 mm, 0.5 mm pitch)



**Note** Mounted on the 96 KB or more code flash memory products.

**Caution** Connect the REGC pin to Vss pin via a capacitor (0.47 to 1  $\mu$ F).

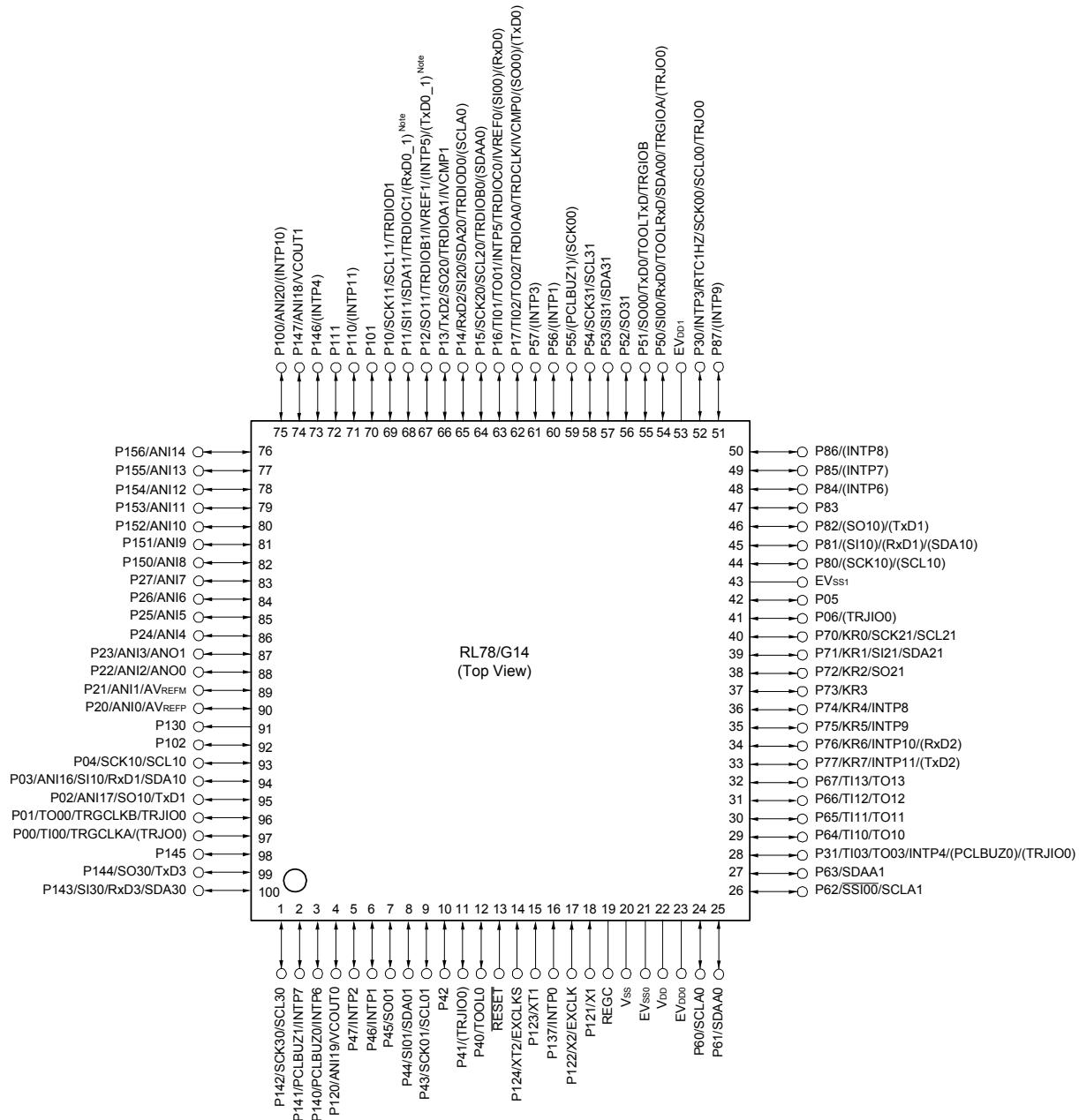
**Remark 1.** For pin identification, see [1.4 Pin Identification](#).

**Remark 2.** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register 0, 1 (PIOR0, 1).

**Remark 3.** It is recommended to connect an exposed die pad to Vss.

### 1.3.10 100-pin products

- 100-pin plastic LFQFP (14 × 14 mm, 0.5 mm pitch)



**Note** Mounted on the 384 KB or more code flash memory products.

**Caution 1.** Make EVss0, EVss1 pins the same potential as Vss pin.

**Caution 2. Make VDD pin the potential that is higher than EVDD0, EVDD1 pins (EVDD0 = EVDD1).**

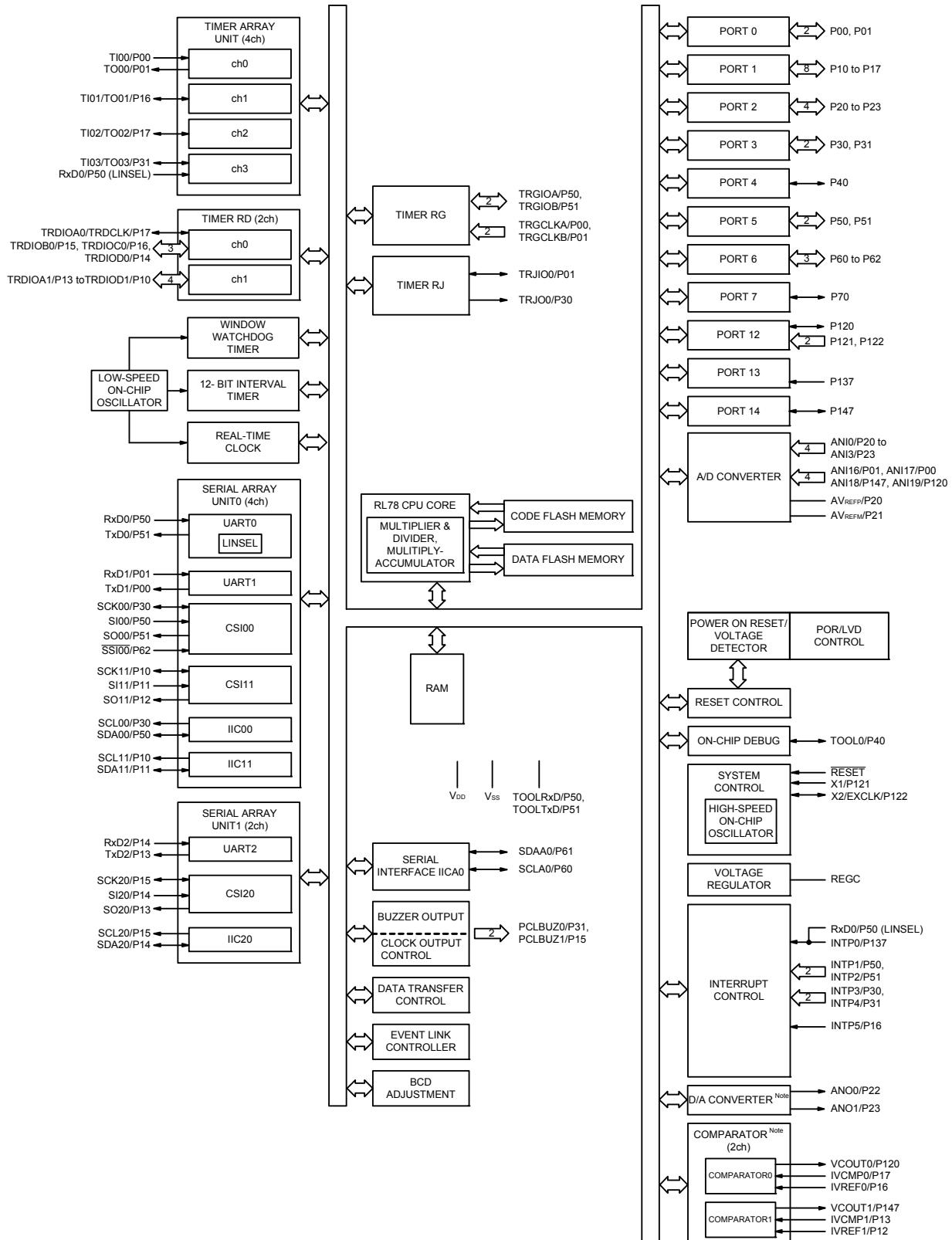
**Caution 3.** Connect the REGC pin to Vss pin via a capacitor (0.47 to 1  $\mu$ F).

**Remark 1.** For pin identification, see [1.4 Pin Identification](#).

**Remark 2.** When using the microcontroller for an application where the noise generated inside the microcontroller must be reduced, it is recommended to supply separate powers to the V<sub>DD</sub>, EV<sub>VDD0</sub> and EV<sub>VDD1</sub> pins and connect the V<sub>SS</sub>, EV<sub>VSS0</sub> and EV<sub>VSS1</sub> pins to separate ground lines.

**Remark 3.** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register 0, 1 (PIOR0, 1).

### 1.5.2 32-pin products



**Note** Mounted on the 96 KB or more code flash memory products.

[30-pin, 32-pin, 36-pin, 40-pin products (code flash memory 96 KB to 256 KB)]

**Caution This outline describes the functions at the time when Peripheral I/O redirection register 0, 1 (PIOR0, 1) are set to 00H.**

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Item	30-pin	32-pin	36-pin	40-pin
	R5F104Ax (x = F, G)	R5F104Bx (x = F, G)	R5F104Cx (x = F, G)	R5F104Ex (x = F to H)
Code flash memory (KB)	96 to 128	96 to 128	96 to 128	96 to 192
Data flash memory (KB)	8	8	8	8
RAM (KB)	12 to 16 Note	12 to 16 Note	12 to 16 Note	12 to 20 Note
Address space	1 MB			
Main system clock	High-speed system clock X1 (crystal/ceramic) oscillation, external main system clock input (EXCLK) HS (high-speed main) mode: 1 to 20 MHz ( $V_{DD}$ = 2.7 to 5.5 V), HS (high-speed main) mode: 1 to 16 MHz ( $V_{DD}$ = 2.4 to 5.5 V), LS (low-speed main) mode: 1 to 8 MHz ( $V_{DD}$ = 1.8 to 5.5 V), LV (low-voltage main) mode: 1 to 4 MHz ( $V_{DD}$ = 1.6 to 5.5 V)			
	High-speed on-chip oscillator clock ( $f_{IH}$ ) HS (high-speed main) mode: 1 to 32 MHz ( $V_{DD}$ = 2.7 to 5.5 V), HS (high-speed main) mode: 1 to 16 MHz ( $V_{DD}$ = 2.4 to 5.5 V), LS (low-speed main) mode: 1 to 8 MHz ( $V_{DD}$ = 1.8 to 5.5 V), LV (low-voltage main) mode: 1 to 4 MHz ( $V_{DD}$ = 1.6 to 5.5 V)			
Subsystem clock		—		XT1 (crystal) oscillation, external subsystem clock input (EXCLKS) 32.768 kHz
Low-speed on-chip oscillator clock	15 kHz (TYP.): $V_{DD}$ = 1.6 to 5.5 V			
General-purpose register	8 bits × 32 registers (8 bits × 8 registers × 4 banks)			
Minimum instruction execution time	0.03125 µs (High-speed on-chip oscillator clock: $f_{IH}$ = 32 MHz operation) 0.05 µs (High-speed system clock: $f_{MX}$ = 20 MHz operation) — 30.5 µs (Subsystem clock: $f_{SUB}$ = 32.768 kHz operation)			
Instruction set	<ul style="list-style-type: none"> <li>• Data transfer (8/16 bits)</li> <li>• Adder and subtractor/logical operation (8/16 bits)</li> <li>• Multiplication (8 bits × 8 bits, 16 bits × 16 bits), Division (16 bits ÷ 16 bits, 32 bits ÷ 32 bits)</li> <li>• Multiplication and Accumulation (16 bits × 16 bits + 32 bits)</li> <li>• Rotate, barrel shift, and bit manipulation (Set, reset, test, and Boolean operation), etc.</li> </ul>			
I/O port	Total	26	28	32
	CMOS I/O	21	22	26
	CMOS input	3	3	3
	CMOS output	—	—	—
	N-ch open-drain I/O (6 V tolerance)	2	3	3
Timer	16-bit timer	8 channels (TAU: 4 channels, Timer RJ: 1 channel, Timer RD: 2 channels, Timer RG: 1 channel)		
	Watchdog timer	1 channel		
	Real-time clock (RTC)	1 channel		
	12-bit interval timer	1 channel		
	Timer output	Timer outputs: 13 channels PWM outputs: 9 channels		
	RTC output	—		1 • 1 Hz (subsystem clock: $f_{SUB}$ = 32.768 kHz)

(Note is listed on the next page.)

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Item	30-pin	32-pin	36-pin	40-pin
	R5F104Ax (x = F, G)	R5F104Bx (x = F, G)	R5F104Cx (x = F, G)	R5F104Ex (x = F to H)
Clock output/buzzer output	2	2	2	2
[30-pin, 32-pin, 36-pin products]				
	<ul style="list-style-type: none"> <li>2.44 kHz, 4.88 kHz, 9.76 kHz, 1.25 MHz, 2.5 MHz, 5 MHz, 10 MHz (Main system clock: <math>f_{MAIN} = 20</math> MHz operation)</li> </ul>			
[40-pin products]				
	<ul style="list-style-type: none"> <li>2.44 kHz, 4.88 kHz, 9.76 kHz, 1.25 MHz, 2.5 MHz, 5 MHz, 10 MHz (Main system clock: <math>f_{MAIN} = 20</math> MHz operation)</li> <li>256 Hz, 512 Hz, 1,024 kHz, 2,048 kHz, 4,096 kHz, 8,192 kHz, 16,384 kHz, 32,768 kHz (Subsystem clock: <math>f_{SUB} = 32,768</math> kHz operation)</li> </ul>			
8/10-bit resolution A/D converter	8 channels	8 channels	8 channels	9 channels
D/A converter	1 channel	2 channels		
Comparator	2 channels			
Serial interface	[30-pin, 32-pin products]			
	<ul style="list-style-type: none"> <li>CSI: 1 channel/UART (UART supporting LIN-bus): 1 channel/simplified I<sup>2</sup>C: 1 channel</li> <li>CSI: 1 channel/UART: 1 channel/simplified I<sup>2</sup>C: 1 channel</li> <li>CSI: 1 channel/UART: 1 channel/simplified I<sup>2</sup>C: 1 channel</li> </ul>			
[36-pin, 40-pin products]				
	<ul style="list-style-type: none"> <li>CSI: 1 channel/UART (UART supporting LIN-bus): 1 channel/simplified I<sup>2</sup>C: 1 channel</li> <li>CSI: 1 channel/UART: 1 channel/simplified I<sup>2</sup>C: 1 channel</li> <li>CSI: 2 channels/UART: 1 channel/simplified I<sup>2</sup>C: 2 channels</li> </ul>			
I <sup>2</sup> C bus	1 channel	1 channel	1 channel	1 channel
Data transfer controller (DTC)	30 sources			31 sources
Event link controller (ELC)	Event input: 21 Event trigger output: 8	Event input: 21, Event trigger output: 9		Event input: 22 Event trigger output: 9
Vectored interrupt sources	Internal	24	24	24
	External	6	6	7
Key interrupt	—	—	—	4
Reset	<ul style="list-style-type: none"> <li>Reset by <math>\overline{RESET}</math> pin</li> <li>Internal reset by watchdog timer</li> <li>Internal reset by power-on-reset</li> <li>Internal reset by voltage detector</li> <li>Internal reset by illegal instruction execution <small>Note</small></li> <li>Internal reset by RAM parity error</li> <li>Internal reset by illegal-memory access</li> </ul>			
Power-on-reset circuit	<ul style="list-style-type: none"> <li>Power-on-reset: <math>1.51 \pm 0.04</math> V (<math>T_A = -40</math> to <math>+85^\circ\text{C}</math>) <math>1.51 \pm 0.06</math> V (<math>T_A = -40</math> to <math>+105^\circ\text{C}</math>)</li> <li>Power-down-reset: <math>1.50 \pm 0.04</math> V (<math>T_A = -40</math> to <math>+85^\circ\text{C}</math>) <math>1.50 \pm 0.06</math> V (<math>T_A = -40</math> to <math>+105^\circ\text{C}</math>)</li> </ul>			
Voltage detector	1.63 V to 4.06 V (14 stages)			
On-chip debug function	Provided			
Power supply voltage	$V_{DD} = 1.6$ to $5.5$ V ( $T_A = -40$ to $+85^\circ\text{C}$ ) $V_{DD} = 2.4$ to $5.5$ V ( $T_A = -40$ to $+105^\circ\text{C}$ )			
Operating ambient temperature	$T_A = -40$ to $+85^\circ\text{C}$ (A: Consumer applications, D: Industrial applications), $T_A = -40$ to $+105^\circ\text{C}$ (G: Industrial applications)			

**Note**

The illegal instruction is generated when instruction code FFH is executed.

Reset by the illegal instruction execution not is issued by emulation with the in-circuit emulator or on-chip debug emulator.

- Note** The flash library uses RAM in self-programming and rewriting of the data flash memory.  
The target products and start address of the RAM areas used by the flash library are shown below.  
R5F104xD (x = A to C, E to G, J, L): Start address FE900H  
R5F104xE (x = A to C, E to G, J, L): Start address FE900H  
For the RAM areas used by the flash library, see **Self RAM list of Flash Self-Programming Library for RL78 Family (R20UT2944)**.

### 2.3.2 Supply current characteristics

#### (1) Flash ROM: 16 to 64 KB of 30- to 64-pin products

(TA = -40 to +85°C, 1.6 V ≤ EV<sub>D0</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>S0</sub> = 0 V)

Parameter	Symbol	Conditions					MIN.	TYP.	MAX.	Unit
Supply current Note 1	IDD1	Operating mode	HS (high-speed main mode Note 5	f <sub>HOCO</sub> = 64 MHz, f <sub>IH</sub> = 32 MHz Note 3	Basic operation	V <sub>DD</sub> = 5.0 V		2.4		mA
						V <sub>DD</sub> = 3.0 V		2.4		
		HS (high-speed main mode Note 5	f <sub>HOCO</sub> = 32 MHz, f <sub>IH</sub> = 32 MHz Note 3	Basic operation	V <sub>DD</sub> = 5.0 V		2.1			mA
						V <sub>DD</sub> = 3.0 V		2.1		
			f <sub>HOCO</sub> = 64 MHz, f <sub>IH</sub> = 32 MHz Note 3	Normal operation	V <sub>DD</sub> = 5.0 V		5.1	8.7		
						V <sub>DD</sub> = 3.0 V		5.1	8.7	
			f <sub>HOCO</sub> = 32 MHz, f <sub>IH</sub> = 32 MHz Note 3	Normal operation	V <sub>DD</sub> = 5.0 V		4.8	8.1		
						V <sub>DD</sub> = 3.0 V		4.8	8.1	
			f <sub>HOCO</sub> = 48 MHz, f <sub>IH</sub> = 24 MHz Note 3	Normal operation	V <sub>DD</sub> = 5.0 V		4.0	6.9		
						V <sub>DD</sub> = 3.0 V		4.0	6.9	
		f <sub>HOCO</sub> = 24 MHz, f <sub>IH</sub> = 24 MHz Note 3	Normal operation	V <sub>DD</sub> = 5.0 V			3.8	6.3		
					V <sub>DD</sub> = 3.0 V		3.8	6.3		
			f <sub>HOCO</sub> = 16 MHz, f <sub>IH</sub> = 16 MHz Note 3	Normal operation	V <sub>DD</sub> = 5.0 V		2.8	4.6		
						V <sub>DD</sub> = 3.0 V		2.8	4.6	
		LS (low-speed main mode Note 5	f <sub>HOCO</sub> = 8 MHz, f <sub>IH</sub> = 8 MHz Note 3	Normal operation	V <sub>DD</sub> = 3.0 V		1.3	2.0		mA
						V <sub>DD</sub> = 2.0 V		1.3	2.0	
		LV (low-voltage main mode Note 5	f <sub>HOCO</sub> = 4 MHz, f <sub>IH</sub> = 4 MHz Note 3	Normal operation	V <sub>DD</sub> = 3.0 V		1.3	1.8		mA
						V <sub>DD</sub> = 2.0 V		1.3	1.8	
		HS (high-speed main mode Note 5	f <sub>MX</sub> = 20 MHz Note 2, V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		3.3	5.3		mA
					Resonator connection		3.4	5.5		
			f <sub>MX</sub> = 20 MHz Note 2, V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		3.3	5.3		
					Resonator connection		3.4	5.5		
			f <sub>MX</sub> = 10 MHz Note 2, V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		2.0	3.1		
					Resonator connection		2.1	3.2		
			f <sub>MX</sub> = 10 MHz Note 2, V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		2.0	3.1		
					Resonator connection		2.1	3.2		
		LS (low-speed main mode Note 5	f <sub>MX</sub> = 8 MHz Note 2, V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		1.2	1.9		mA
					Resonator connection		1.2	2.0		
			f <sub>MX</sub> = 8 MHz Note 2, V <sub>DD</sub> = 2.0 V	Normal operation	Square wave input		1.2	1.9		
					Resonator connection		1.2	2.0		
		Subsystem clock operation	f <sub>SUB</sub> = 32.768 kHz Note 4 TA = -40°C	Normal operation	Square wave input		4.7	6.1		μA
					Resonator connection		4.7	6.1		
			f <sub>SUB</sub> = 32.768 kHz Note 4 TA = +25°C	Normal operation	Square wave input		4.7	6.1		
					Resonator connection		4.7	6.1		
			f <sub>SUB</sub> = 32.768 kHz Note 4 TA = +50°C	Normal operation	Square wave input		4.8	6.7		
					Resonator connection		4.8	6.7		
			f <sub>SUB</sub> = 32.768 kHz Note 4 TA = +70°C	Normal operation	Square wave input		4.8	7.5		
					Resonator connection		4.8	7.5		
			f <sub>SUB</sub> = 32.768 kHz Note 4 TA = +85°C	Normal operation	Square wave input		5.4	8.9		
					Resonator connection		5.4	8.9		

(Notes and Remarks are listed on the next page.)

## (4) During communication at same potential (CSI mode) (slave mode, SCKp... external clock input)

(TA = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)

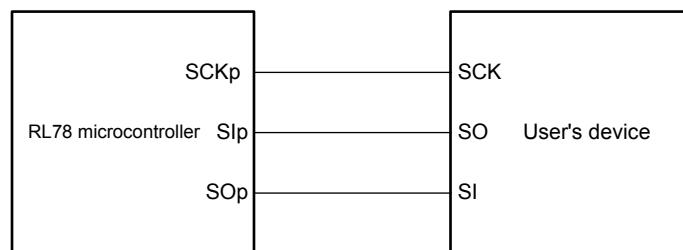
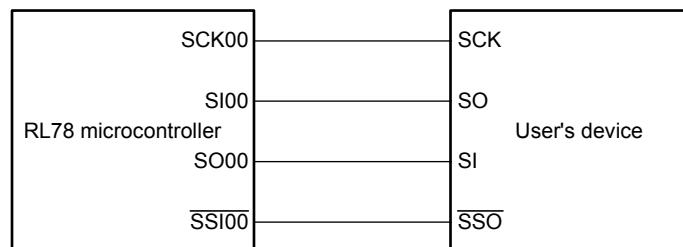
(2/2)

Parameter	Symbol	Conditions	HS (high-speed main) mode		LS (low-speed main) mode		LV (low-voltage main) mode		Unit	
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
SSI00 setup time	tssik	DAPmn = 0	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	120		120		120		ns
			1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	200		200		200		ns
			1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	400		400		400		ns
			1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	—		400		400		ns
		DAPmn = 1	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	1/fMCK + 120		1/fMCK + 120		1/fMCK + 120		ns
			1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	1/fMCK + 200		1/fMCK + 200		1/fMCK + 200		ns
			1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	1/fMCK + 400		1/fMCK + 400		1/fMCK + 400		ns
			1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	—		1/fMCK + 400		1/fMCK + 400		ns
SSI00 hold time	tkssi	DAPmn = 0	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	1/fMCK + 120		1/fMCK + 120		1/fMCK + 120		ns
			1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	1/fMCK + 200		1/fMCK + 200		1/fMCK + 200		ns
			1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	1/fMCK + 400		1/fMCK + 400		1/fMCK + 400		ns
			1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	—		1/fMCK + 400		1/fMCK + 400		ns
		DAPmn = 1	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	120		120		120		ns
			1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	200		200		200		ns
			1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	400		400		400		ns
			1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	—		400		400		ns

**Caution** Select the normal input buffer for the Slp pin and SCKp pin and the normal output mode for the SOOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

**Remark** p: CSI number (p = 00), m: Unit number (m = 0), n: Channel number (n = 0), g: PIM number (g = 3, 5)

## CSI mode connection diagram (during communication at same potential)

CSI mode connection diagram (during communication at same potential)  
(Slave Transmission of slave select input function (CSI00))

**Remark 1.** p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31)

**Remark 2.** m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13)

**(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output)**

(TA = -40 to +85°C, 1.8 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, Vss = EVSS0 = EVSS1 = 0 V) (3/3)

Parameter	Symbol	Conditions	HS (high-speed main mode)		LS (low-speed main mode)		LV (low-voltage main mode)		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Slp setup time (to SCKp↓) Note 1	tsIK1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ	44		110		110		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 30 pF, Rb = 2.7 kΩ	44		110		110		ns
		1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V Note 2, Cb = 30 pF, Rb = 5.5 kΩ	110		110		110		ns
Slp hold time (from SCKp↓) Note 1	tksI1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ	19		19		19		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 30 pF, Rb = 2.7 kΩ	19		19		19		ns
		1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V Note 2, Cb = 30 pF, Rb = 5.5 kΩ	19		19		19		ns
Delay time from SCKp↑ to SOp output Note 1	tksO1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ		25		25		25	ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 30 pF, Rb = 2.7 kΩ		25		25		25	ns
		1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V Note 2, Cb = 30 pF, Rb = 5.5 kΩ		25		25		25	ns

**Note 1.** When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Note 2.** Use it with EVDD0 ≥ Vb.

**Caution** Select the TTL input buffer for the Slp pin and the N-ch open drain output (VDD tolerance (for the 30- to 52-pin products)/EVDD tolerance (for the 64- to 100-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and Vil, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

- (2) When reference voltage (+) = AVREFP/ANI0 (ADREFP1 = 0, ADREFP0 = 1), reference voltage (-) = AVREFM/ANI1 (ADREFM = 1), target pin: ANI16 to ANI20

(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, 1.6 V ≤ AVREFP ≤ VDD ≤ 5.5 V, Vss = EVSS0 = EVSS1 = 0 V, Reference voltage (+) = AVREFP, Reference voltage (-) = AVREFM = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	RES			8		10	bit
Overall error Note 1	AINL	10-bit resolution EVDD0 ≤ AVREFP = VDD Notes 3, 4	1.8 V ≤ AVREFP ≤ 5.5 V		1.2	±5.0	LSB
			1.6 V ≤ AVREFP ≤ 5.5 V Note 5		1.2	±8.5	LSB
Conversion time	tCONV	10-bit resolution Target ANI pin: ANI16 to ANI20	3.6 V ≤ VDD ≤ 5.5 V	2.125		39	μs
			2.7 V ≤ VDD ≤ 5.5 V	3.1875		39	μs
			1.8 V ≤ VDD ≤ 5.5 V	17		39	μs
			1.6 V ≤ VDD ≤ 5.5 V	57		95	μs
Zero-scale error Notes 1, 2	Ezs	10-bit resolution EVDD0 ≤ AVREFP = VDD Notes 3, 4	1.8 V ≤ AVREFP ≤ 5.5 V			±0.35	%FSR
			1.6 V ≤ AVREFP ≤ 5.5 V Note 5			±0.60	%FSR
Full-scale error Notes 1, 2	Efs	10-bit resolution EVDD0 ≤ AVREFP = VDD Notes 3, 4	1.8 V ≤ AVREFP ≤ 5.5 V			±0.35	%FSR
			1.6 V ≤ AVREFP ≤ 5.5 V Note 5			±0.60	%FSR
Integral linearity error Note 1	ILE	10-bit resolution EVDD0 ≤ AVREFP = VDD Notes 3, 4	1.8 V ≤ AVREFP ≤ 5.5 V			±3.5	LSB
			1.6 V ≤ AVREFP ≤ 5.5 V Note 5			±6.0	LSB
Differential linearity error Note 1	DLE	10-bit resolution EVDD0 ≤ AVREFP = VDD Notes 3, 4	1.8 V ≤ AVREFP ≤ 5.5 V			±2.0	LSB
			1.6 V ≤ AVREFP ≤ 5.5 V Note 5			±2.5	LSB
Analog input voltage	VAIN	ANI16 to ANI20		0		AVREFP and EVDD0	V

**Note 1.** Excludes quantization error (±1/2 LSB).

**Note 2.** This value is indicated as a ratio (%FSR) to the full-scale value.

**Note 3.** When EVDD0 ≤ AVREFP ≤ VDD, the MAX. values are as follows.

Overall error: Add ±1.0 LSB to the MAX. value when AVREFP = VDD.

Zero-scale error/Full-scale error: Add ±0.05%FSR to the MAX. value when AVREFP = VDD.

Integral linearity error/ Differential linearity error: Add ±0.5 LSB to the MAX. value when AVREFP = VDD.

**Note 4.** When AVREFP < EVDD0 ≤ VDD, the MAX. values are as follows.

Overall error: Add ±4.0 LSB to the MAX. value when AVREFP = VDD.

Zero-scale error/Full-scale error: Add ±0.20%FSR to the MAX. value when AVREFP = VDD.

Integral linearity error/ Differential linearity error: Add ±2.0 LSB to the MAX. value when AVREFP = VDD.

**Note 5.** When the conversion time is set to 57 μs (min.) and 95 μs (max.).

## 2.6.4 Comparator

(TA = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>VSS0</sub> = EV<sub>VSS1</sub> = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Input voltage range	I <sub>Vref</sub>			0		EV <sub>DD0</sub> - 1.4	V
	I <sub>Vcmp</sub>			-0.3		EV <sub>DD0</sub> + 0.3	V
Output delay	t <sub>d</sub>	V <sub>DD</sub> = 3.0 V Input slew rate > 50 mV/μs	Comparator high-speed mode, standard mode			1.2	μs
			Comparator high-speed mode, window mode			2.0	μs
			Comparator low-speed mode, standard mode		3.0	5.0	μs
High-electric-potential reference voltage	V <sub>TW+</sub>	Comparator high-speed mode, window mode			0.76 V <sub>DD</sub>		V
Low-electric-potential ref- erence voltage	V <sub>TW-</sub>	Comparator high-speed mode, window mode			0.24 V <sub>DD</sub>		V
Operation stabilization wait time	t <sub>CMP</sub>			100			μs
Internal reference voltage Note	V <sub>BGR</sub>	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V, HS (high-speed main) mode		1.38	1.45	1.50	V

**Note** Not usable in LS (low-speed main) mode, LV (low-voltage main) mode, sub-clock operation, or STOP mode.

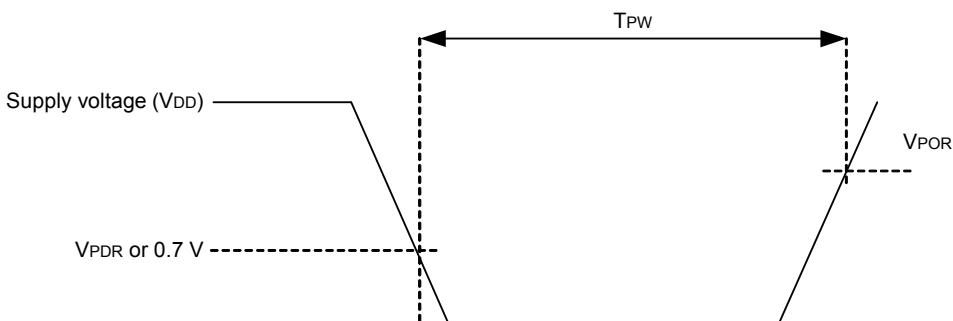
## 2.6.5 POR circuit characteristics

(TA = -40 to +85°C, V<sub>SS</sub> = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Power on/down reset threshold	V <sub>POR</sub>	Voltage threshold on V <sub>DD</sub> rising	1.47	1.51	1.55	V
	V <sub>PDR</sub>	Voltage threshold on V <sub>DD</sub> falling Note 1	1.46	1.50	1.54	V
Minimum pulse width Note 2	T <sub>PW</sub>		300			μs

**Note 1.** However, when the operating voltage falls while the LVD is off, enter STOP mode, or enable the reset status using the external reset pin before the voltage falls below the operating voltage range shown in 2.4 AC Characteristics.

**Note 2.** Minimum time required for a POR reset when V<sub>DD</sub> exceeds below V<sub>PDR</sub>. This is also the minimum time required for a POR reset from when V<sub>DD</sub> exceeds below 0.7 V to when V<sub>DD</sub> exceeds V<sub>POR</sub> while STOP mode is entered or the main system clock is stopped through setting bit 0 (HIOSTOP) and bit 7 (MSTOP) in the clock operation status control register (CSC).



**(2) Interrupt & Reset Mode**

(TA = -40 to +85°C, VPDR ≤ VDD ≤ 5.5 V, Vss = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Voltage detection threshold	VLVDA0	VPOC2, VPOC1, VPOCO = 0, 0, 0, falling reset voltage		1.60	1.63	1.66	V
	VLVDA1	LVIS1, LVIS0 = 1, 0	Rising release reset voltage	1.74	1.77	1.81	V
			Falling interrupt voltage	1.70	1.73	1.77	V
	VLVDA2	LVIS1, LVIS0 = 0, 1	Rising release reset voltage	1.84	1.88	1.91	V
			Falling interrupt voltage	1.80	1.84	1.87	V
	VLVDA3	LVIS1, LVIS0 = 0, 0	Rising release reset voltage	2.86	2.92	2.97	V
			Falling interrupt voltage	2.80	2.86	2.91	V
	VLVDB0	VPOC2, VPOC1, VPOCO = 0, 0, 1, falling reset voltage		1.80	1.84	1.87	V
	VLVDB1	LVIS1, LVIS0 = 1, 0	Rising release reset voltage	1.94	1.98	2.02	V
			Falling interrupt voltage	1.90	1.94	1.98	V
	VLVDB2	LVIS1, LVIS0 = 0, 1	Rising release reset voltage	2.05	2.09	2.13	V
			Falling interrupt voltage	2.00	2.04	2.08	V
	VLVDB3	LVIS1, LVIS0 = 0, 0	Rising release reset voltage	3.07	3.13	3.19	V
			Falling interrupt voltage	3.00	3.06	3.12	V
Voltage detection threshold	VLVDC0	VPOC2, VPOC1, VPOCO = 0, 1, 0, falling reset voltage		2.40	2.45	2.50	V
	VLVDC1	LVIS1, LVIS0 = 1, 0	Rising release reset voltage	2.56	2.61	2.66	V
			Falling interrupt voltage	2.50	2.55	2.60	V
	VLVDC2	LVIS1, LVIS0 = 0, 1	Rising release reset voltage	2.66	2.71	2.76	V
			Falling interrupt voltage	2.60	2.65	2.70	V
	VLVDC3	LVIS1, LVIS0 = 0, 0	Rising release reset voltage	3.68	3.75	3.82	V
			Falling interrupt voltage	3.60	3.67	3.74	V
	VLVDD0	VPOC2, VPOC1, VPOCO = 0, 1, 1, falling reset voltage		2.70	2.75	2.81	V
	VLVDD1	LVIS1, LVIS0 = 1, 0	Rising release reset voltage	2.86	2.92	2.97	V
			Falling interrupt voltage	2.80	2.86	2.91	V
	VLVDD2	LVIS1, LVIS0 = 0, 1	Rising release reset voltage	2.96	3.02	3.08	V
			Falling interrupt voltage	2.90	2.96	3.02	V
	VLVDD3	LVIS1, LVIS0 = 0, 0	Rising release reset voltage	3.98	4.06	4.14	V
			Falling interrupt voltage	3.90	3.98	4.06	V

**2.6.7 Power supply voltage rising slope characteristics**

(TA = -40 to +85°C, Vss = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Power supply voltage rising slope	SVDD				54	V/ms

**Caution** Make sure to keep the internal reset state by the LVD circuit or an external reset until Vdd reaches the operating voltage range shown in 2.4 AC Characteristics.

### 3. ELECTRICAL SPECIFICATIONS (G: INDUSTRIAL APPLICATIONS $T_A = -40$ to $+105^\circ C$ )

This chapter describes the following electrical specifications.

Target products G: Industrial applications  $T_A = -40$  to  $+105^\circ C$

R5F104xxGxx

**Caution 1.** The RL78 microcontrollers have an on-chip debug function, which is provided for development and evaluation. Do not use the on-chip debug function in products designated for mass production, because the guaranteed number of rewritable times of the flash memory may be exceeded when this function is used, and product reliability therefore cannot be guaranteed. Renesas Electronics is not liable for problems occurring when the on-chip debug function is used.

**Caution 2.** With products not provided with an EVDD0, EVDD1, EVSS0, or EVSS1 pin, replace EVDD0 and EVDD1 with VDD, or replace EVSS0 and EVSS1 with Vss.

**Caution 3.** The pins mounted depend on the product. Refer to 2.1 Port Functions to 2.2.1 Functions for each product in the RL78/G14 User's Manual.

**Caution 4.** Please contact Renesas Electronics sales office for derating of operation under  $T_A = +85$  to  $+105^\circ C$ . Derating is the systematic reduction of load for the sake of improved reliability.

**Remark** When RL78/G14 is used in the range of  $T_A = -40$  to  $+85^\circ C$ , see 2. ELECTRICAL SPECIFICATIONS ( $T_A = -40$  to  $+85^\circ C$ ).

(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

(2/2)

Items	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Timer RD input high-level width, low-level width	tTDIH, tTDIL	TRDIOA0, TRDIOA1, TRDIOB0, TRDIOB1, TRDIODC0, TRDIODC1, TRDIOD0, TRDIOD1		3/fCLK			ns
Timer RD forced cutoff signal input low-level width	tTDSIL	P130/INTP0	2MHz < fCLK ≤ 32 MHz	1			μs
			fCLK ≤ 2 MHz	1/fCLK + 1			
Timer RG input high-level width, low-level width	tTRGIH, tTGIL	TRGIOA, TRGIOB		2.5/fCLK			ns
TO00 to TO03, TO10 to TO13, TRJIO0, TRJOO, TRDIOA0, TRDIOA1, TRDIOB0, TRDIOB1, TRDIODC0, TRDIODC1, TRDIOD0, TRDIOD1, TRGIOA, TRGIOB output frequency	fro	HS (high-speed main) mode	4.0 V ≤ EVDD0 ≤ 5.5 V			16	MHz
			2.7 V ≤ EVDD0 < 4.0 V			8	MHz
			2.4 V ≤ EVDD0 < 2.7 V			4	MHz
PCLBUZ0, PCLBUZ1 output frequency	fPCL	HS (high-speed main) mode	4.0 V ≤ EVDD0 ≤ 5.5 V			16	MHz
			2.7 V ≤ EVDD0 < 4.0 V			8	MHz
			2.4 V ≤ EVDD0 < 2.7 V			4	MHz
Interrupt input high-level width, low-level width	tINTH, tINTL	INTP0	2.4 V ≤ VDD ≤ 5.5 V	1			μs
		INTP1 to INTP11	2.4 V ≤ EVDD0 ≤ 5.5 V	1			μs
Key interrupt input low-level width	tKR	KR0 to KR7	2.4 V ≤ EVDD0 ≤ 5.5 V	250			ns
RESET low-level width	tRSI			10			μs

**(2) During communication at same potential (CSI mode) (master mode, SCKp... internal clock output)**(TA = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)

Parameter	Symbol	Conditions		HS (high-speed main) mode		Unit
				MIN.	MAX.	
SCKp cycle time	tkCY1	tkCY1 ≥ 4/fCLK	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	250		ns
			2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	500		ns
SCKp high-/low-level width	tKH1, tKL1	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		tkCY1/2 - 24		ns
		2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		tkCY1/2 - 36		ns
		2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		tkCY1/2 - 76		ns
Slp setup time (to SCKp↑) Note 1	tSIK1	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		66		ns
		2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		66		ns
		2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		113		ns
Slp hold time (from SCKp↓) Note 2	tKS1			38		ns
Delay time from SCKp↓ to SOp output Note 3	tKS01	C = 30 pF Note 4			50	ns

**Note 1.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes “to SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Note 2.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes “from SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Note 3.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes “from SCKp↑” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

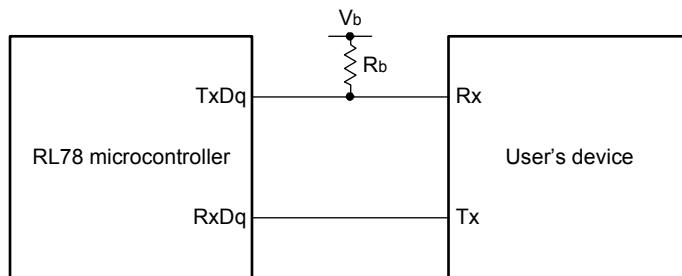
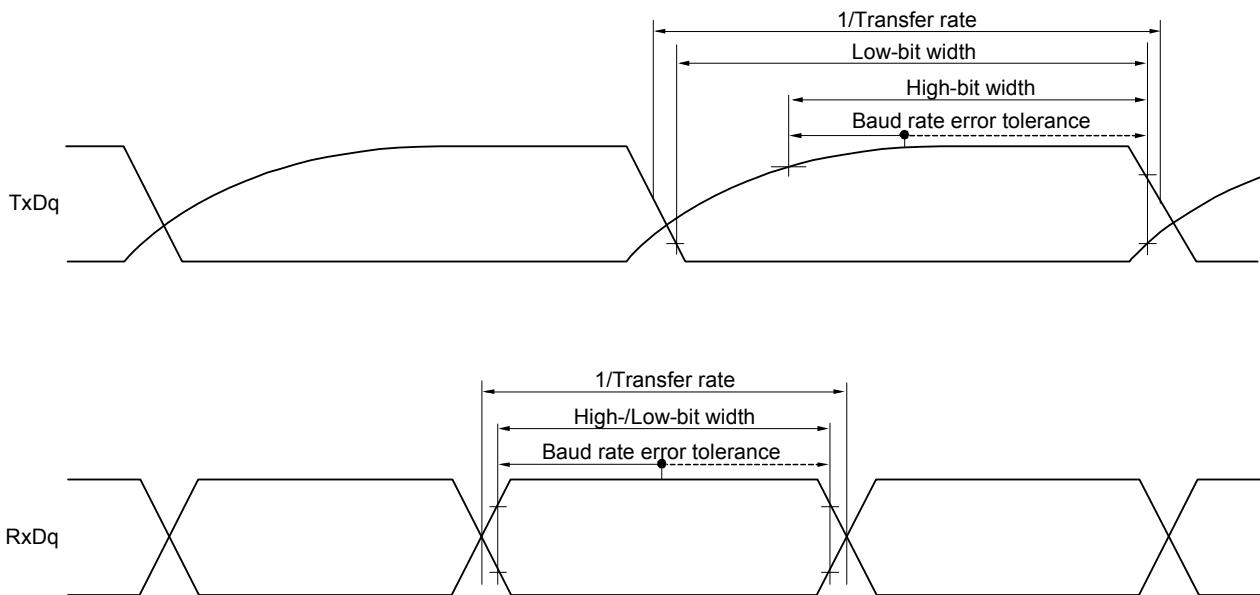
**Note 4.** C is the load capacitance of the SCKp and SOp output lines.

**Caution** Select the normal input buffer for the Slp pin and the normal output mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

**Remark 1.** p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3), g: PIM number (g = 0, 1, 3 to 5, 14)

**Remark 2.** fmCK: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))

**UART mode connection diagram (during communication at different potential)****UART mode bit width (during communication at different potential) (reference)**

**Remark 1.**  $R_b[\Omega]$ : Communication line (TxDq) pull-up resistance,  
 $C_b[F]$ : Communication line (TxDq) load capacitance,  $V_b[V]$ : Communication line voltage

**Remark 2.** q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 5, 14)

**Remark 3.** fmck: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn)).

m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))

**Remark 4.** UART2 cannot communicate at different potential when bit 1 (PIOR01) of peripheral I/O redirection register 0 (PIOR0) is 1.

**(2) Interrupt & Reset Mode**

(TA = -40 to +105°C, VPDR ≤ VDD ≤ 5.5 V, Vss = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Voltage detection threshold	V <sub>LVDD0</sub>	V <sub>POC2</sub> , V <sub>POC1</sub> , V <sub>Poco</sub> = 0, 1, 1, falling reset voltage		2.64	2.75	2.86	V
	V <sub>LVDD1</sub>	LVIS1, LVIS0 = 1, 0	Rising release reset voltage	2.81	2.92	3.03	V
			Falling interrupt voltage	2.75	2.86	2.97	V
	V <sub>LVDD2</sub>	LVIS1, LVIS0 = 0, 1	Rising release reset voltage	2.90	3.02	3.14	V
			Falling interrupt voltage	2.85	2.96	3.07	V
	V <sub>LVDD3</sub>	LVIS1, LVIS0 = 0, 0	Rising release reset voltage	3.90	4.06	4.22	V
			Falling interrupt voltage	3.83	3.98	4.13	V

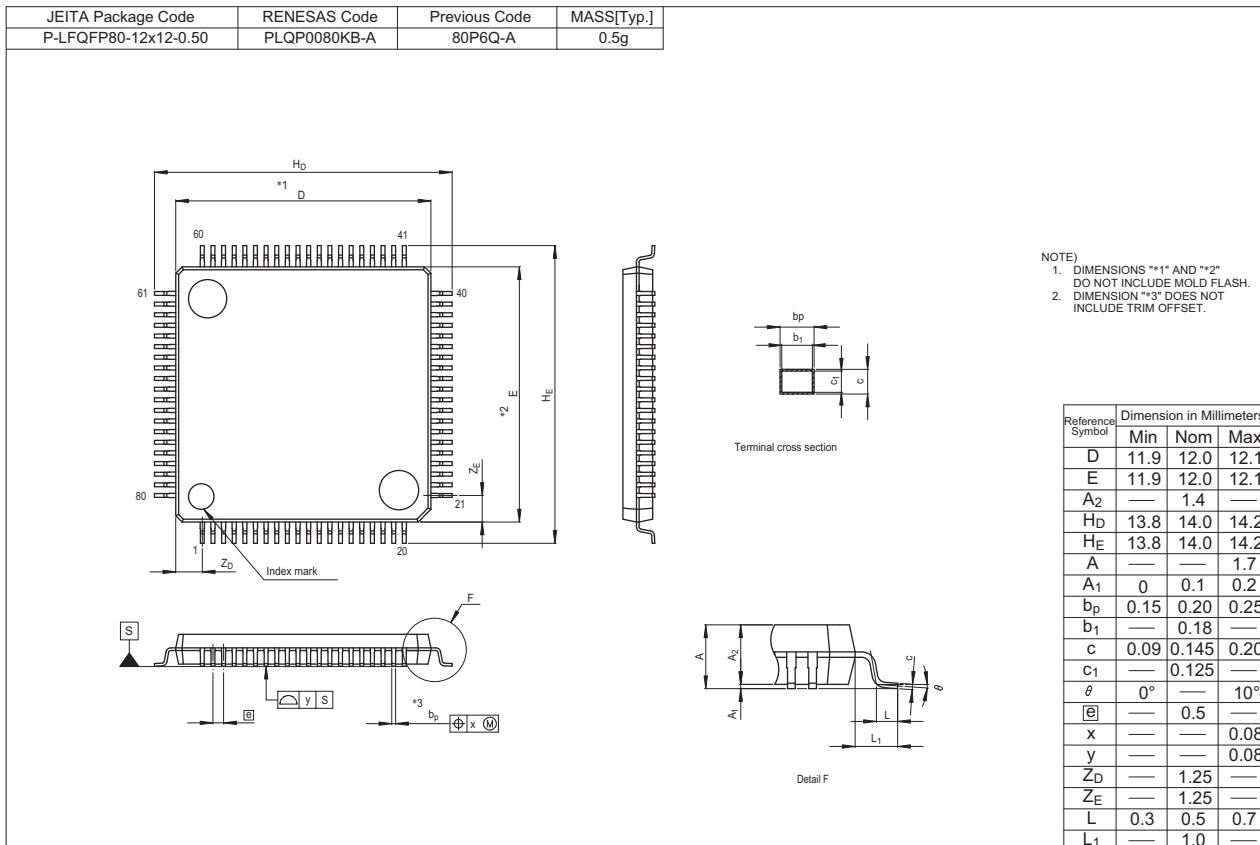
**3.6.7 Power supply voltage rising slope characteristics**

(TA = -40 to +105°C, Vss = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Power supply voltage rising slope	S <sub>VDD</sub>				54	V/ms

**Caution** Make sure to keep the internal reset state by the LVD circuit or an external reset until Vdd reaches the operating voltage range shown in 3.4 AC Characteristics.

R5F104MKAFB, R5F104MLAFB  
R5F104MKGFB, R5F104MLGFB



REVISION HISTORY		RL78/G14 Datasheet	
Rev.	Date	Description	
		Page	Summary
2.00	Oct 25, 2013	112 to 169	Addition of CHAPTER 3 ELECTRICAL SPECIFICATIONS
3.00	Feb 07, 2014	171 to 187	Modification of 4.1 30-pin products to 4.10 100-pin products
		All	Addition of products with maximum 512 KB flash ROM and 48 KB RAM
		1	Modification of 1.1 Features
		2	Modification of ROM, RAM capacities and addition of note 3
		3	Modification of Figure 1 - 1 Part Number, Memory Size, and Package of RL78/G14
		6 to 8	Addition of part number
		15, 16	Modification of 1.3.6 48-pin products
		17	Modification of 1.3.7 52-pin products
		18, 19	Modification of 1.3.8 64-pin products
		20	Modification of 1.3.9 80-pin products
		21, 22	Modification of 1.3.10 100-pin products
		35, 37, 39, 41, 43, 45, 47	Modification of operating ambient temperature in 1.6 Outline of Functions
		42, 43	Addition of table of 48-pin, 52-pin, 64-pin products (code flash memory 384 KB to 512 KB)
		46, 47	Addition of table of 80-pin, 100-pin products (code flash memory 384 KB to 512 KB)
		65 to 68	Addition of (3) Flash ROM: 384 to 512 KB of 48- to 100-pin products
		118	Modification of 2.7 Data Memory Retention Characteristics
		137 to 140	Addition of (3) Flash ROM: 384 to 512 KB of 48- to 100-pin products
		180	Modification of 3.7 Data Memory Retention Characteristics
		189, 190	Addition and modification of 4.6 48-pin products
		191	Modification of 4.7 52-pin products
		193 to 195	Addition and modification of 4.8 64-pin products
		198, 199	Addition and modification of 4.9 80-pin products
		201, 202	Addition and modification of 4.10 100-pin products
3.20	Jan 05, 2015	p.2	Deletion of R5F104JK and R5F104JL from the list of ROM and RAM capacities and modification of note
		p.6	Deletion of ordering part numbers of R5F104JK and R5F104JL from 52-pin plastic LQFP package in 1.2 Ordering Information
		p.6 to 8	Deletion of note 2 in 1.2 Ordering Information
		p.17	Deletion of note 2 in 1.3.7 52-pin products
		p.36, 39, 42, 45, 48, 50, 52	Modification of description in 1.6 Outline of Functions
		p.46, 48	Deletion of description of 52-pin in 1.6 Outline of Functions
		p.47	Modification of note of 1.6 Outline of Functions
		p.62, 64, 66, 68, 70, 72	Modification of specifications in 2.3.2 Supply current characteristics